

#### 3.2mmx1.6mm SMD CHIP LED LAMP

Part Number: APT3216EC Hi

High Efficiency Red

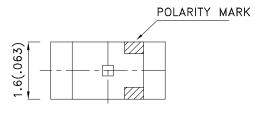
#### **Features**

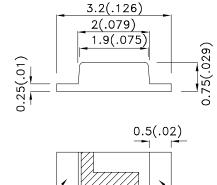
- 3.2mmx1.6mm SMT LED, 0.75mm THICKNESS.
- LOW POWER CONSUMPTION.
- WIDE VIEWING ANGLE.
- IDEAL FOR BACKLIGHT AND INDICATOR.
- VARIOUS COLORS AND LENS TYPES AVAILABLE.
- PACKAGE: 2000PCS / REEL.
- MOISTURE SENSITIVITY LEVEL: LEVEL 3.
- RoHS COMPLIANT.

#### Description

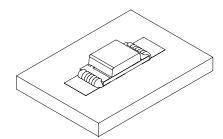
The High Efficiency Red source color devices are made with Gallium Arsenide Phosphide on Gallium Phosphide Orange Light Emitting Diode.

### **Package Dimensions**









- 1. All dimensions are in millimeters (inches).
- 2. Tolerance is ±0.2(0.008") unless otherwise noted.
- 3. Specifications are subject to change without notice.
- 4. The device has a single mounting surface. The device must be mounted according to the specifications.





 SPEC NO: DSAD0986
 REV NO: V.8
 DATE: MAY/07/2007
 PAGE: 1 OF 5

 APPROVED: WYNEC
 CHECKED: Allen Liu
 DRAWN: Y.L.LI
 ERP: 1203001913

### **Selection Guide**

Part No.	Dice	Lens Type	lv (mcd) [2] @ 20mA		Viewing Angle [1]
			Min.	Тур.	201/2
APT3216EC	High Efficiency Red (GaAsP/GaP)	WATER CLEAR	4	12	120°

#### Notes:

- 1. 01/2 is the angle from optical centerline where the luminous intensity is 1/2 the optical centerline value.
  2. Luminous intensity/ luminous Flux: +/-15%.

### Electrical / Optical Characteristics at TA=25°C

Symbol	Parameter	Device	Тур.	Max.	Units	Test Conditions
λpeak	Peak Wavelength	High Efficiency Red	627		nm	IF=20mA
λD [1]	Dominant Wavelength	High Efficiency Red	625		nm	IF=20mA
Δλ1/2	Spectral Line Half-width	High Efficiency Red	45		nm	IF=20mA
С	Capacitance	High Efficiency Red	15		pF	V <sub>F</sub> =0V;f=1MHz
VF [2]	Forward Voltage	High Efficiency Red	2	2.5	V	I=20mA
lr	Reverse Current	High Efficiency Red		10	uA	V <sub>R</sub> =5V

#### Notes:

1.Wavelength: +/-1nm. 2. Forward Voltage: +/-0.1V.

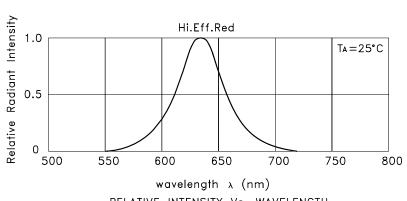
#### Absolute Maximum Ratings at TA=25°C

And of the control of						
arameter	High Efficiency Red	Units				
Power dissipation	75	mW				
OC Forward Current	30	mA				
eak Forward Current [1]	160	mA				
Reverse Voltage	5	V				
perating Temperature	-40°C To +85°C					
Storage Temperature	-40°C To +85°C					
torage Temperature	nperature -40°C To +85°C					

#### Note:

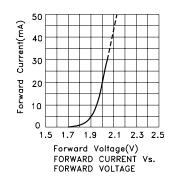
1. 1/10 Duty Cycle, 0.1ms Pulse Width.

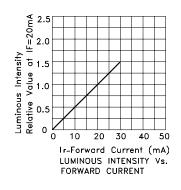
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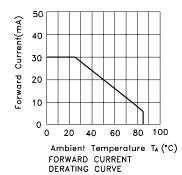


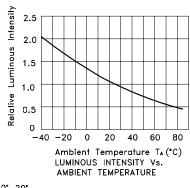
RELATIVE INTENSITY Vs. WAVELENGTH

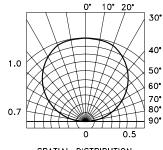
#### **High Efficiency Red APT3216EC**









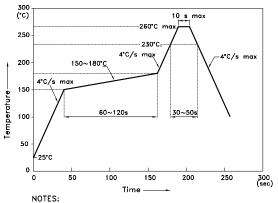


SPATIAL DISTRIBUTION

SPEC NO: DSAD0986 **REV NO: V.8** DATE: MAY/07/2007 PAGE: 3 OF 5 APPROVED: WYNEC **CHECKED: Allen Liu** ERP: 1203001913 DRAWN: Y.L.LI

## **APT3216EC**

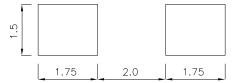
Reflow Soldering Profile For Lead-free SMT Process.



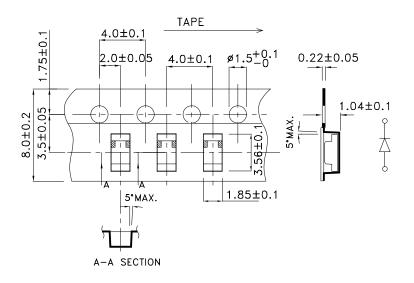
- NOTES:

  1.We recommend the reflow temperature 245°C(+/-5°C).The maximum soldering temperature should be limited to 260°C. 2.Don't cause stress to the epoxy resin while it is exposed to high temperature.
   3.Number of reflow process shall be 2 times or less.

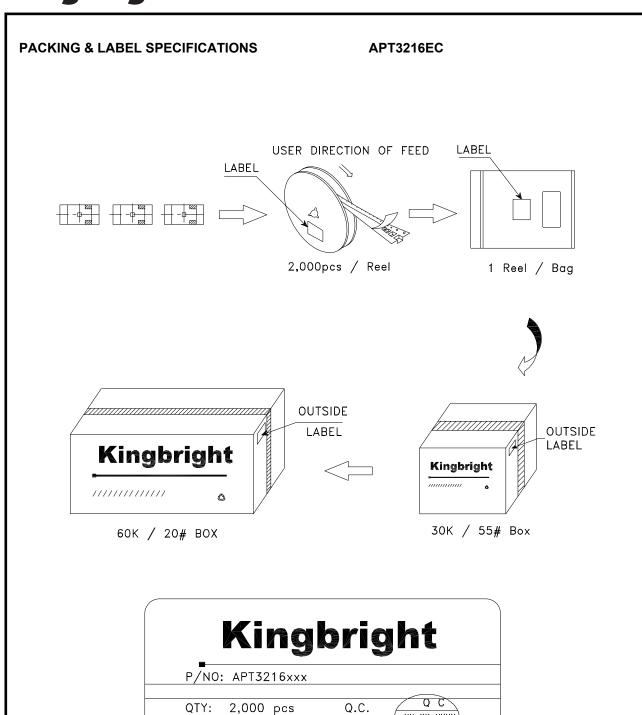
**Recommended Soldering Pattern** (Units: mm; Tolerance: ± 0.1)



### **Tape Specifications** (Units: mm)



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SPEC NO: DSAD0986 APPROVED: WYNEC

**REV NO: V.8 CHECKED: Allen Liu** 

S/N:

CODE: XXX

MADE IN CHINA

LOT NO:

DATE: MAY/07/2007 DRAWN: Y.L.LI

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PASSED

RoHS Compliant

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